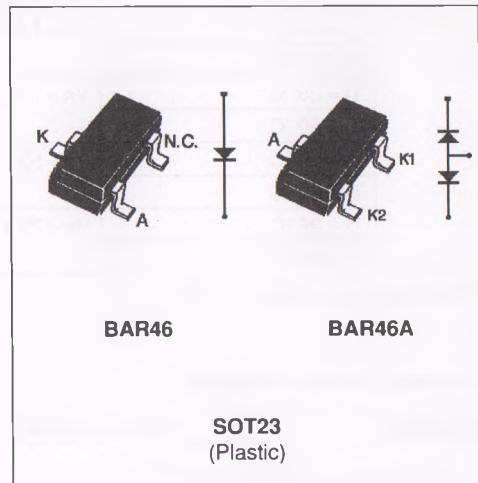


SMALL SIGNAL SCHOTTKY DIODES


DESCRIPTION

High voltage Schottky rectifier suited for SLIC protection during the card insertion operation.

ABSOLUTE RATINGS(limiting values)

Symbol	Parameter	Value	Unit
V _{RMM}	Repetitive Peak Reverse Voltage	100	V
P _{tot}	Power Dissipation * Tamb=25°C	200	mW
T _{stg} T _j	Storage and Junction Temperature Range	-55 to + 150 150	°C

THERMAL RESISTANCE

Symbol	Parameter	Value	Unit
R _{th(j-a)}	Junction-ambient *	625	°C/W
R _{th(j-SR)}	Junction-Substrate	400	°C/W

* Mounted on ceramic substrate : 7 x 5 x 0.5mm

ELECTRICAL CHARACTERISTICS

STATIC CHARACTERISTICS

Symbol	Test conditions		Min.	Typ.	Max.	Unit
V_{BR}	$T_j = 25^\circ C$	$I_R = 100 \mu A$	100			V
V_F *	$T_j = 25^\circ C$	$I_F = 0.1 mA$			0.25	V
	$T_j = 25^\circ C$	$I_F = 10 mA$			0.45	
	$T_j = 25^\circ C$	$I_F = 250 mA$			1	
I_R *	$T_j = 25^\circ C$	$V_R = 1.5 V$			0.5	μA
	$T_j = 60^\circ C$				5	
	$T_j = 25^\circ C$	$V_R = 10 V$			0.8	
	$T_j = 60^\circ C$				7.5	
	$T_j = 25^\circ C$	$V_R = 50 V$			2	
	$T_j = 60^\circ C$				15	
	$T_j = 25^\circ C$	$V_R = 75 V$			5	
	$T_j = 60^\circ C$				20	

* Pulse test : $t_p \leq 300\mu s$ $\delta < 2\%$

DYNAMIC CHARACTERISTICS

Symbol	Test conditions			Min.	Typ.	Max.	Unit
C	$T_j = 25^\circ C$	$V_R = 0 V$	$f = 1MHz$		10		pF
	$T_j = 25^\circ C$	$V_R = 1 V$			6		

Type	BAR46	BAR46A
Marking	S46	A46

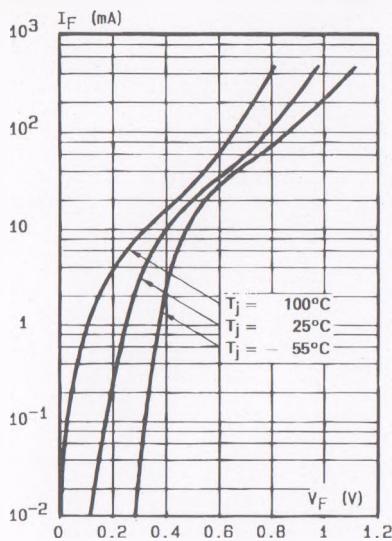


Fig.1 - Forward current versus forward voltage at different temperatures (typical values).

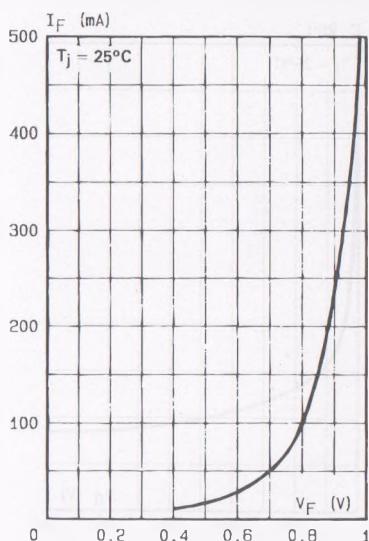


Fig.2 - Forward current versus forward voltage (typical values).

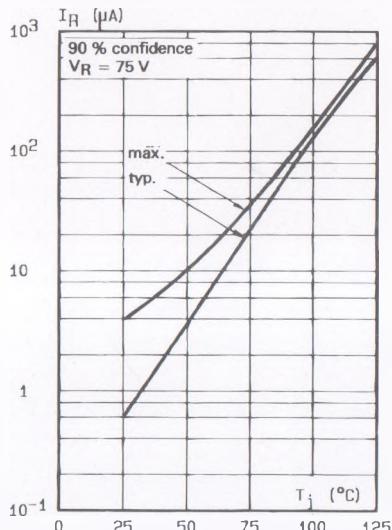


Fig.3 - Reverse current versus junction temperature (typical values).

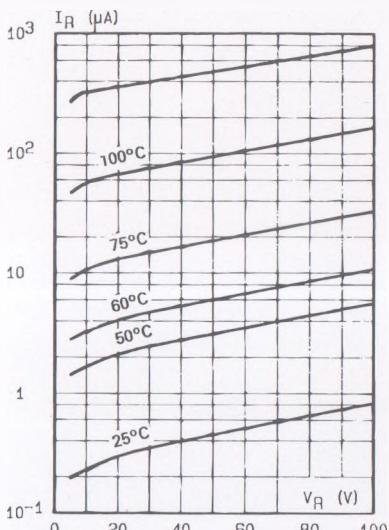


Fig.4 - Reverse current versus continuous reverse voltage.

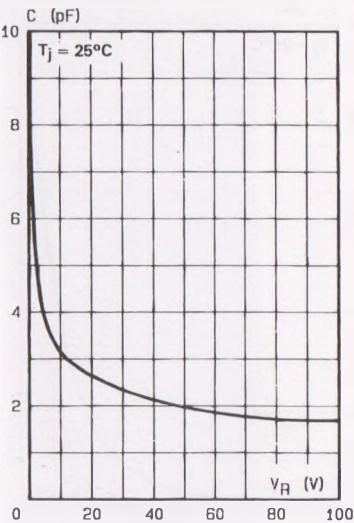


Fig.5 - Capacitance C versus
reverse applied voltage V_R
(typical values).